

## 肖特基二极管 SBR ( Schottky Barrier Rectifiers )

肖特基二极管是利用金属半导体接触面上形成的势垒具有整流特性而制成的金属-半导体器件。作为低压，高频整流器或者整流桥，极性保护二极管，适用于紧凑型，小型的系统。典型应用于AC-DC和DC-DC转换器，电池极性保护，多种电压“ORing”和其他小尺寸系统的应用。



A Schottky Barrier Rectifier is a metal-semiconductor device fabricated by utilizing a rectifying property of a barrier formed on a metal semiconductor contact surface. This device is suitable for compact and small size systems. Typical for AC-DC and DC-DC converters, battery-polarity protection, multiple voltage ‘ORING’ and other small size systems.

## 特点 Features

- ▲ 极低正向压降，VF Very low forward voltage-drop, VF
- ▲ 因极低正向电压实现高效率 High efficiency due to extremely low forward voltage
- ▲ 高连续电流功能，IF High continuous current capability, IF
- ▲ 可节省空间的小型和超小型表面贴装封装 Small and ultra small, low profile surface mount package for economic use of space
- ▲ 高峰值电流功能，IFSM High peak current capability, IFSM
- ▲ 卓越的尺寸/性能比，以及更长的电池使用时间 Excellent size / performance ratio together with extended battery life
- ▲ 低功耗和低发热 Low power dissipation and low heat generation
- ▲ 结合低反向电流的高速开关 High-speed switching combined with low reverse current
- ▲ 耐用的设计和较长的产品使用寿命 Robust designs and long product lifetime

## 应用 Application

- ▲ 中小功率整流  
Low and medium power rectification
- ▲ 电源管理电路，尤其是DC转DC转换  
Power management circuits, especially DC-to-DC conversion
- ▲ 反向极性保护  
Reverse polarity protection
- ▲ 低功耗应用  
Low power application
- ▲ 用于继电器和电机的电感负载的续流二极管  
Free wheeling diode for inductive loads in motors and relays

## Definitions and Terms

$V_{RRM}$	Maximum Recurrent Peak Reverse Voltage
$V_{RMS}$	Maximum RMS Voltage
$V_{DC}$	Maximum DC Blocking Voltage
$I_{F(AV)}$	Maximum Average Forward Current at $T_L=75^\circ\text{C}$
$I_{FSM}$	Peak Forward Surge Current :8.3ms single half sine-wave superimposed on rated load (JEDEC method)
$V_F$	Maximum Forward Voltage at 1.0A
$I_R$	Maximum DC Reverse Current at Rated DC Blocking Voltage
$R_{\theta JL}$	Typical Thermal Resistance — Junction-to-Lead
$R_{\theta JA}$	Typical Thermal Resistance — Junction-to-Ambient
$T_J, T_{STR}$	Operating Junction and Storage Temperature Range

## Electrical Characteristics - SMA (1A) Series

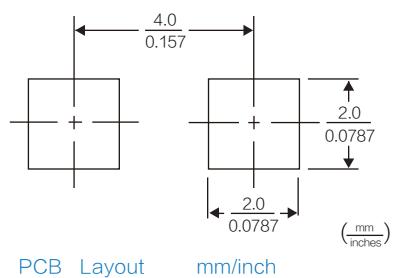
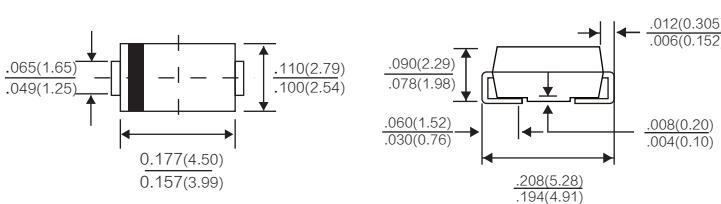
Parameter	$V_{RRM}$ V	$V_{RRS}$ V	$V_{DC}$ V	$I_{F(AV)}$ A	$I_{FSM}$ A	$V_F^*$ V	IR(MA)		$R_{\theta JL}^*$ °C/W	$R_{\theta JA}$ °C/W	$T_J, T_{STR}$ °C
							25°C	100°C			
SS12	20	14	20	1.0	30	0.5	0.2	50	28	88	-55to+125
SS13	30	21	30	1.0	30	0.5	0.2	50	28	88	-55to+125
SS14	40	28	40	1.0	30	0.7	0.05	10	30	88	-55to+125
SS15	50	35	50	1.0	30	0.74	0.05	10	30	88	-65to+125
SS16	60	42	60	1.0	30	0.74	0.05	10	30	88	-65to+125
SS18	80	56	80	1.0	30	0.80	0.05	5	30	88	-65to+125
SS19	90	63	90	1.0	30	0.80	0.05	5	30	88	-65to+125
SS110	100	70	100	1.0	30	0.80	0.05	5	30	88	-65to+125
SS115	150	105	150	1.0	30	0.90	0.02	2	30	88	-65to+125
SS120	200	140	200	1.0	30	0.90	0.02	2	30	88	-65to+125

## NOTES:

\*.Pulse Test with PW = 300 usec ,1% Duty Cycle

\*.Mounted on P.C. Board with 5.0mm<sup>2</sup> copper pad areas .

## SMA 产品尺寸 (Dimension Unit: mm ) Dimensions in inches and (millimeters)



### Electrical Characteristics - SMA/SMB ( 2A ) Series



Parameter	V <sub>R<sup>RM</sup></sub> V	V <sub>R<sup>RS</sup></sub> V	V <sub>D<sup>C</sup></sub> V	I <sub>F(AV)</sub> A	I <sub>FSM</sub> A	V <sub>F</sub> * V	I <sub>R</sub> (MA)		R <sub>θJL</sub> * °C/W	R <sub>θJA</sub> °C/W	T <sub>J,TSTR</sub> °C
	25°C	100°C									
SS22	20	14	20	2.0	50	0.5	0.2	20	20	75	-55to+125
SS23	30	21	30	2.0	50	0.5	0.2	20	20	75	-55to+125
SS24	40	28	40	2.0	50	0.7	0.05	20	20	75	-55to+150
SS25	50	35	50	2.0	50	0.7	0.05	20	20	75	-65to+150
SS26	60	42	60	2.0	50	0.7	0.05	20	20	75	-65to+175
SS28	80	56	80	2.0	50	0.80	0.05	20	20	75	-65to+175
SS29	90	63	90	2.0	50	0.80	0.05	20	20	75	-65to+175
SS210	100	70	100	2.0	50	0.80	0.05	20	20	75	-65to+175
SS215	150	105	150	2.0	50	0.90	0.05	20	20	75	-65to+175
SS220	200	140	200	2.0	50	0.90	0.05	20	20	75	-65to+175

NOTES:

\*.Pulse Test with PW = 300 usec , 1% Duty Cycle

\*.Mounted on P.C. Board with 8.0mm<sup>2</sup> copper pad areas .

### Electrical Characteristics - SMA/SMB ( 3A ) Series



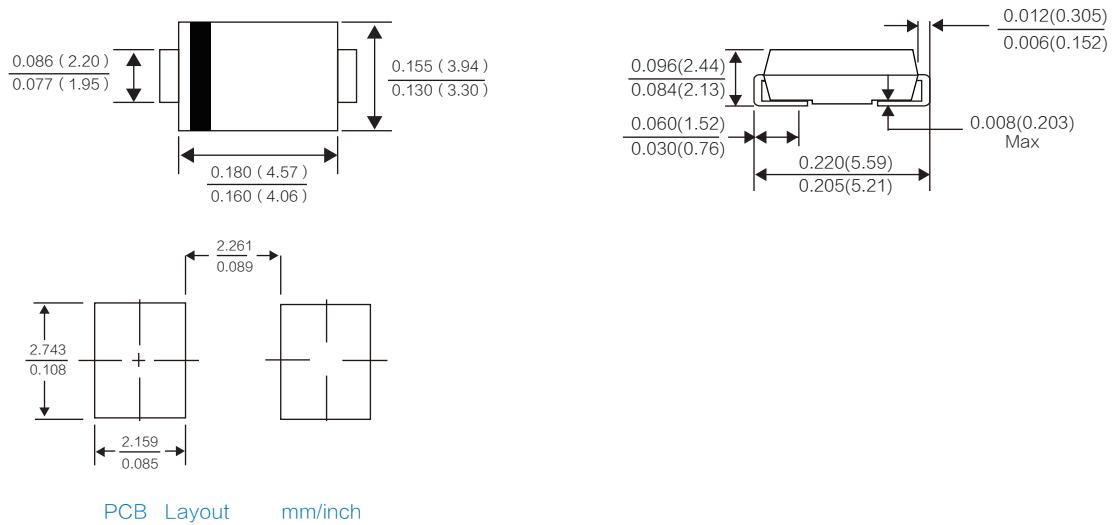
Parameter	V <sub>R<sup>RM</sup></sub> V	V <sub>R<sup>RS</sup></sub> V	V <sub>D<sup>C</sup></sub> V	I <sub>F(AV)</sub> A	I <sub>FSM</sub> A	V <sub>F</sub> * V	I <sub>R</sub> (MA)		R <sub>θJL</sub> * °C/W	R <sub>θJA</sub> °C/W	T <sub>J,TSTR</sub> °C
	25°C	100°C									
SS32	20	14	20	3.0	80	0.5	0.2	20	20	75	-55to+125
SS33	30	21	30	3.0	80	0.5	0.2	20	20	75	-55to+125
SS34	40	28	40	3.0	80	0.7	0.05	20	20	75	-55to+150
SS35	50	35	50	3.0	80	0.74	0.05	20	20	75	-65to+175
SS36	60	42	60	3.0	80	0.74	0.05	20	20	75	-65to+175
SS38	80	56	80	3.0	80	0.80	0.05	20	20	75	-65to+175
SS39	90	63	90	3.0	80	0.80	0.05	20	20	75	-65to+175
SS310	100	70	100	3.0	80	0.80	0.05	20	20	75	-65to+175
SS315	150	105	150	3.0	80	0.90	0.05	20	20	75	-65to+175
SS320	200	140	200	3.0	80	0.90	0.05	20	20	75	-65to+175

NOTES:

\*.Pulse Test with PW = 300 usec , 1% Duty Cycle

\*.Mounted on P.C. Board with 8.0mm<sup>2</sup> copper pad areas .

## SMB 产品尺寸 (Dimension Unit: inch / mm)



## Electrical Characteristics – SMC ( 3A ) Series



Parameter	V <sub>R<sub>RM</sub></sub> V	V <sub>R<sub>RS</sub></sub> V	V <sub>DC</sub> V	I <sub>F(AV)</sub> A	I <sub>FSM</sub> A	V <sub>F</sub> * V	I <sub>R</sub> (MA)		R <sub>θJL</sub> * °C/W	R <sub>θJA</sub> °C/W	T <sub>J</sub> , T <sub>STR</sub> °C
	25°C	100°C									
SK32	20	14	20	3.0	100	0.5	0.2	20	20	75	-55to+125
SK33	30	21	30	3.0	100	0.5	0.2	20	20	75	-55to+125
SK34	40	28	40	3.0	100	0.7	0.05	20	20	75	-55to+150
SK35	50	35	50	3.0	100	0.74	0.05	20	20	75	-65to+175
SK36	60	42	60	3.0	100	0.74	0.05	20	20	75	-65to+175
SK38	80	56	80	3.0	100	0.80	0.05	20	20	75	-65to+175
SK39	90	63	90	3.0	100	0.80	0.05	20	20	75	-65to+175
SK310	100	70	100	3.0	100	0.80	0.05	20	20	75	-65to+175
SK315	150	105	150	3.0	100	0.90	0.05	20	20	75	-65to+175
SK320	200	140	200	3.0	100	0.90	0.05	20	20	75	-65to+175

## NOTES:

\*.Pulse Test with PW = 300 usec ,1% Duty Cycle

\*.Mounted on P.C. Board with 8.0mm<sup>2</sup> copper pad areas .

## Electrical Characteristics - SMC ( 5A ) Series



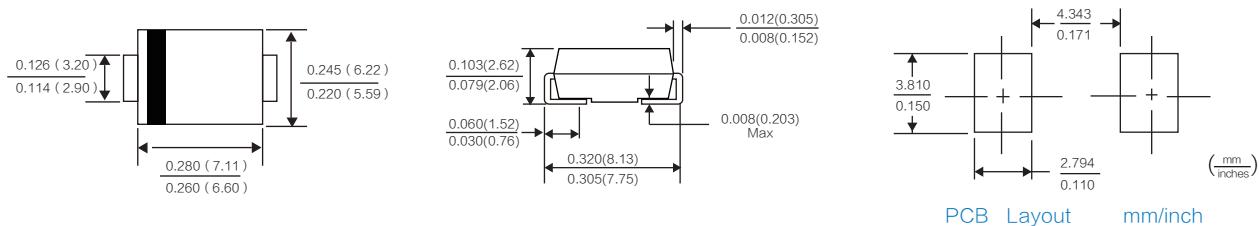
Parameter	V <sub>R<sup>RM</sup></sub> V	V <sub>R<sup>RS</sup></sub> V	V <sub>DC</sub> V	I <sub>F(AV)</sub> A	I <sub>FSM</sub> A	V <sub>F</sub> * V	I <sub>R</sub> (mA)		R <sub>θJL</sub> * °C/W	R <sub>θJA</sub> °C/W	T <sub>J</sub> ,T <sub>STR</sub> °C
	25°C	100°C									
SK52	20	14	20	5.0	100	0.55	0.2	20	17	55	-55to+125
SK53	30	21	30	5.0	100	0.55	0.2	20	17	55	-55to+125
SK54	40	28	40	5.0	100	0.7	0.05	10	17	55	-55to+150
SK55	50	35	50	5.0	100	0.74	0.05	10	17	55	-65to+175
SK56	60	42	60	5.0	100	0.74	0.05	10	17	55	-65to+175
SK58	80	56	80	5.0	100	0.80	0.05	10	17	55	-65to+175
SK59	90	63	90	5.0	100	0.80	0.05	10	17	55	-65to+175
SK510	100	70	100	5.0	100	0.80	0.05	10	17	55	-65to+175
SK515	150	105	150	5.0	100	0.90	0.05	10	17	55	-65to+175
SK520	200	140	200	5.0	100	0.90	0.05	10	17	55	-65to+175

## NOTES:

\*.Pulse Test with PW = 300 usec , 1% Duty Cycle

 \*.Mounted on P.C. Board with 8.0mm<sup>2</sup> copper pad areas

## SMC/Do-214AB 产品尺寸 (Dimension Unit: mm ) Dimensions in inches and (millimeters)

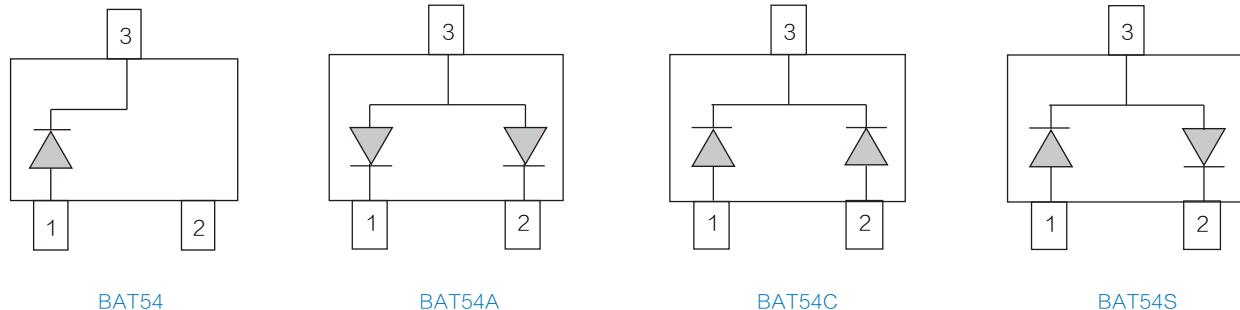


## Electrical Characteristics - SOT23 Series



PARAMETER	SYMBOL	BAT54	BAT54A	BAT54C	BAT54S	UNITS
Forward Power Dissipation@TA=25°C	P <sub>D</sub>			225		mW
Repetitive Peak Reverse Voltage	V <sub>R<sup>RM</sup></sub>		30			V
Maximum Average Forward Current at T <sub>L</sub> =75 °C	I <sub>F(AV)</sub>		0.2			A
Repetitive Peak Forward Current (TP=8.3ms .50% Duty Cycle)	I <sub>FRM</sub>		300			mA
Peak Forward Surge Current 1.0s (JEDEC method)	I <sub>FSM</sub>		0.6			A
Maximum Instantaneous Forward Voltage @I <sub>F</sub> =1mA , @I <sub>F</sub> =100mA	V <sub>F</sub>		0.32	0.8		V
Maximum DC Reverse Current at Rated DC Blocking Voltage@VR=25V	I <sub>R</sub>		2.0			uA
Thermal Resistance , Junction to Ambient	R <sub>θJA</sub>		500			°C/W
Junction Capacitance @ VR=1V	C <sub>J</sub>		10			PF
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STR</sub>		-55 to +125			°C

## Circuit



## Rating &amp; Characteristic Curves

Figure 1- Forward Current Derating Curve

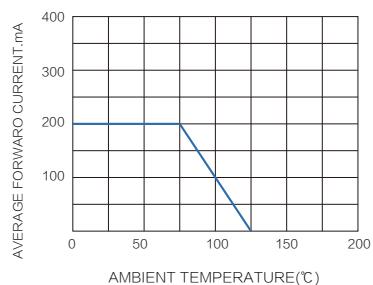


Figure 2- Typical Junction capacitance

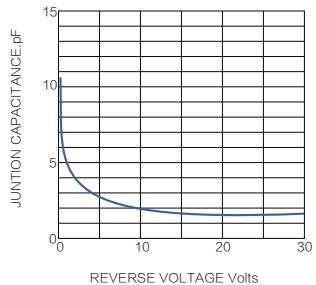


Figure 3- Typical Reverse Characteristics

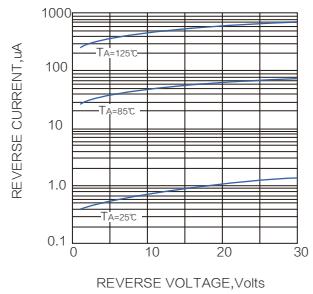


Figure 4 – Instantaneous Forward Characteristics

